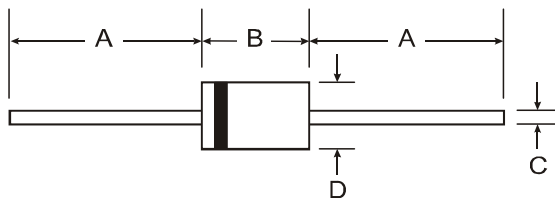


Features

- Diffused Junction
- Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Reverse Leakage Current
- **Lead Free Finish, RoHS compliant (Note 4)**



Mechanical Data

- Case: DO-41
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish - Tin. Plated Leads Solderable per MIL-STD-202, Method 208 
- Polarity: Cathode Band
- Marking: Type Number
- Ordering Information: See Page 3
- Weight: 0.35 grams (approximate)

Dim	DO-41 Plastic	
	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics

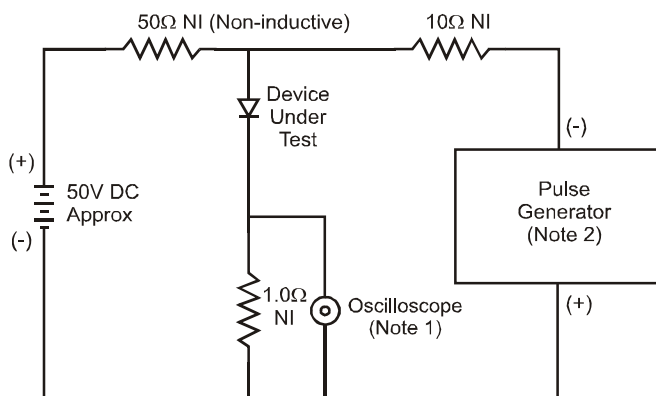
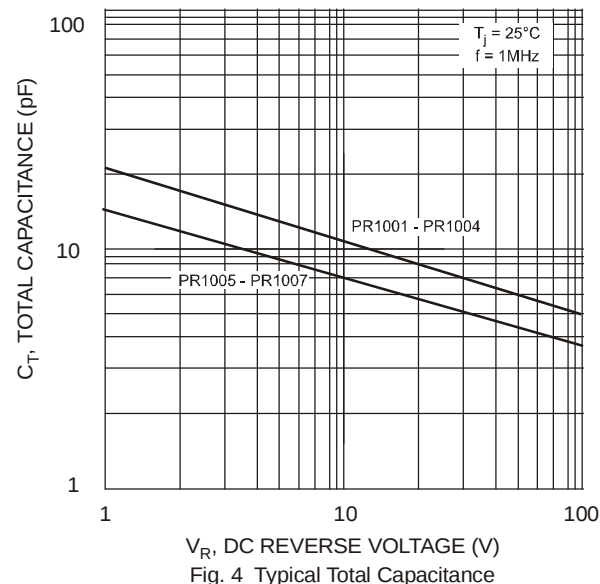
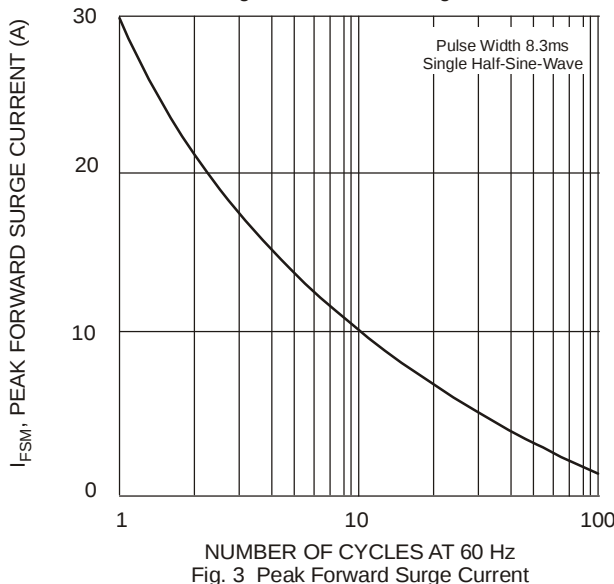
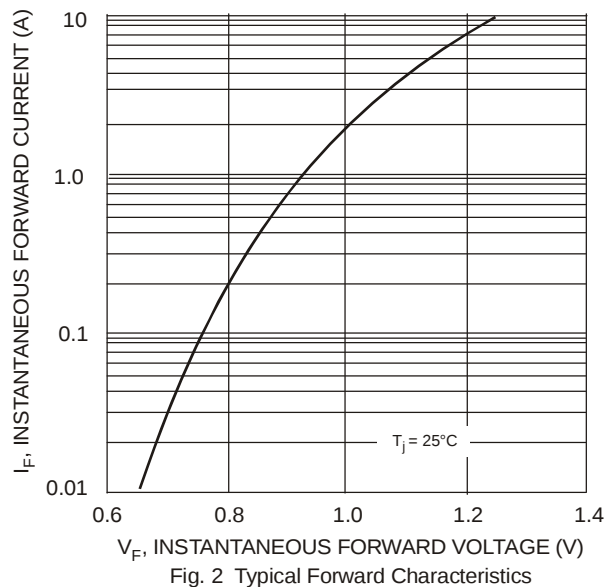
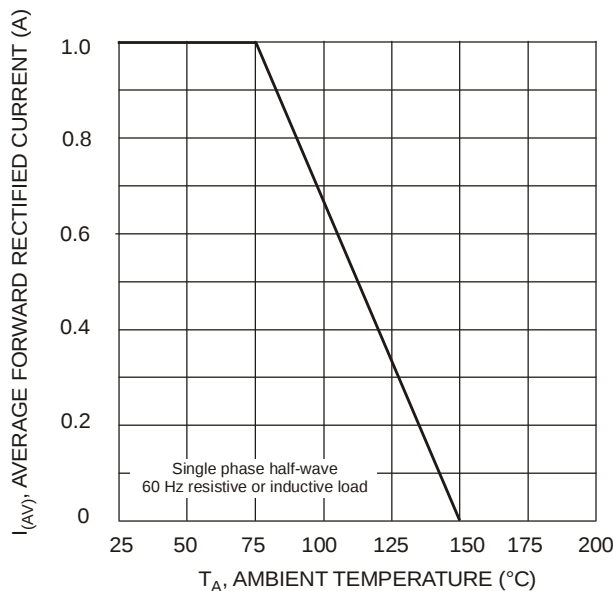
@T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	PR1001	PR1002	PR1003	PR1004	PR1005	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	50	100	200	400	600	V
Working Peak Reverse Voltage	V _{RWM}						
DC Blocking Voltage (Note 5)	V _R						
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	V
Average Rectified Output Current (Note 1) @ T _A = 75°C	I _O	1.0					A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	30					A
Forward Voltage Drop @ I _F = 1.0A	V _{FM}	1.2					V
Peak Reverse Current @ T _A = 25°C at Rated DC Blocking Voltage (Note 5) @ T _A = 100°C	I _{RM}	5.0 100					μA
Reverse Recovery Time (Note 3)	t _{rr}	150				250	ns
Typical Total Capacitance (Note 2)	C _T	15				8.0	pF
Typical Thermal Resistance Junction to Ambient	R _{θJA}	75					°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150					°C

- Notes:
1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Measured with I_F = 0.5A, I_R = 1A, I_{rr} = 0.25A. See figure 5.
 4. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
 5. Short duration pulse test used to minimize self-heating effect.



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MW, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50W.

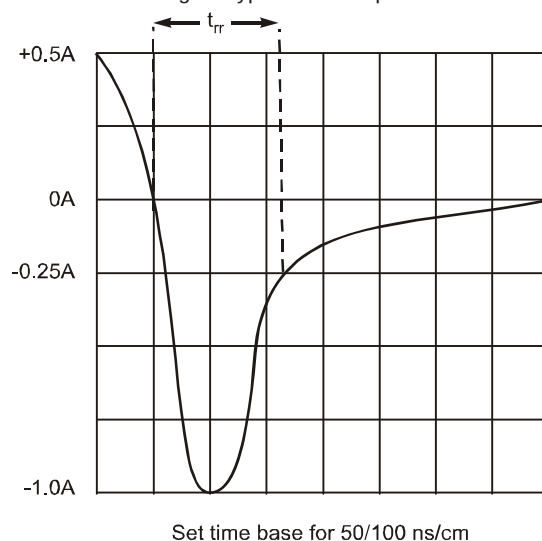


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

Ordering Information (Note 6)

Device	Packaging	Shipping
PR1001-T	DO-41	5K/Tape & Reel, 13-inch
PR1002-T	DO-41	5K/Tape & Reel, 13-inch
PR1003-T	DO-41	5K/Tape & Reel, 13-inch
PR1004-T	DO-41	5K/Tape & Reel, 13-inch
PR1005-T	DO-41	5K/Tape & Reel, 13-inch

Notes: 6. For packaging details, visit our website at <http://www.diodes.com/datasheets/ap02008.pdf>.

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9